



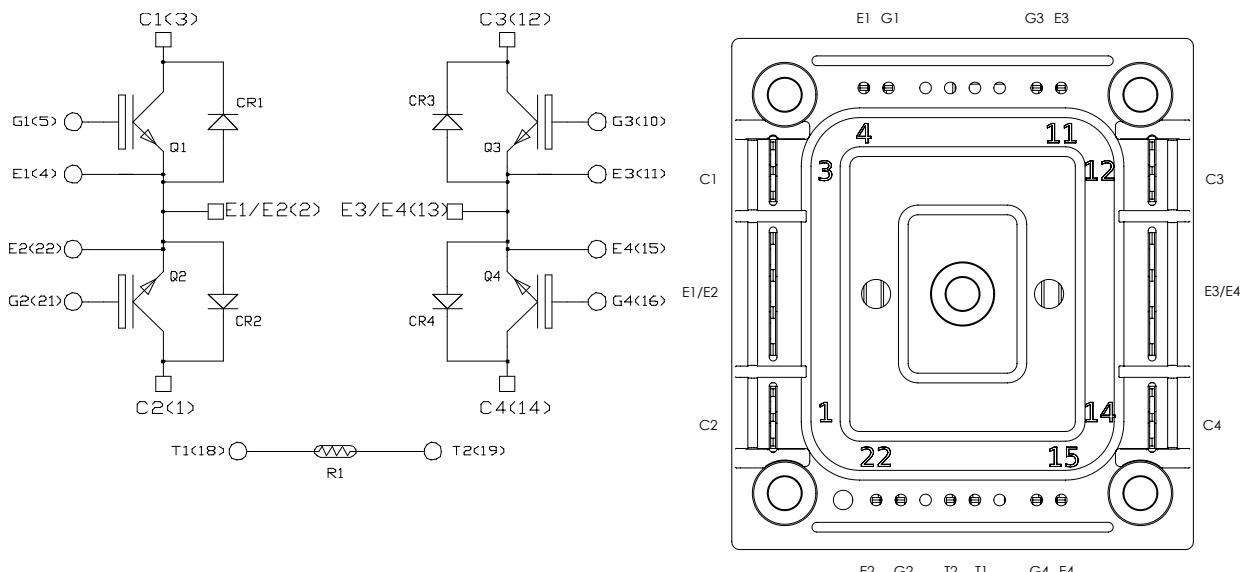
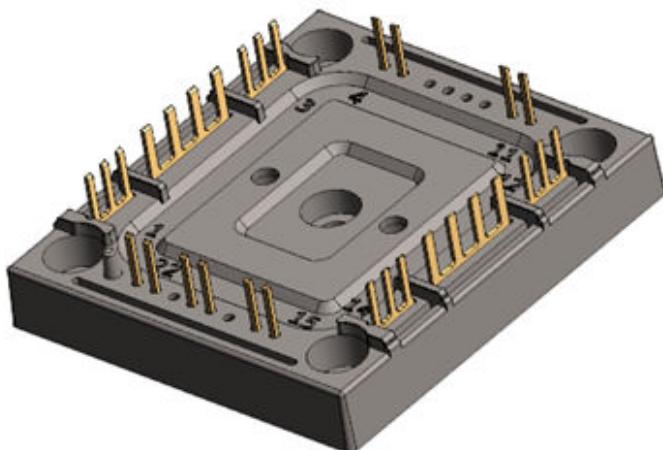
MICROCHIP

**MSCGLQ75DDU120CTBL3NG**

## Double Dual Common Emitter High-Speed IGBT4 Power Module

### Product Overview

The MSCGLQ75DDU120CTBL3NG device is a 1200 V/75 A double dual common emitter high-speed IGBT4 power module.



All ratings at  $T_J = 25^\circ\text{C}$ , unless otherwise specified.

**Caution:** These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

## **Features**

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The following are the key features of MSCGLQ75DDU120CTBL3NG device:

- High speed IGBT4
  - Low voltage drop
  - Low leakage current
  - Low switching losses
- SiC Schottky Diode
  - Zero reverse recovery
  - Zero forward recovery
  - Temperature independent switching behavior
  - Positive temperature coefficient on  $V_F$
- Ultra-low weight and profile
- Kelvin emitter for easy drive
- $\text{Si}_3\text{N}_4$  substrate with thick copper for improved thermal performance
- Internal thermistor for temperature monitoring
- Extended temperature range

## **Benefits**

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The following are the benefits of MSCGLQ75DDU120CTBL3NG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-heatsink thermal resistance
- Low profile
- RoHS compliant
- Solderable terminals both for power and signal for easy PCB mounting
- Very integrated power conversion system

## **Application**

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The following are the applications of MSCGLQ75DDU120CTBL3NG device:

- High reliability power systems
- AC switches

## 1. Electrical Specifications

This section provides the electrical specifications of MSCGLQ75DDU120CTBL3NG device.

### 1.1 IGBT4 Characteristics (Per IGBT)

The following table lists the absolute maximum ratings of MSCGLQ75DDU120CTBL3NG device.

**Table 1-1. Absolute Maximum Ratings**

Symbol	Parameter	Maximum Ratings		Unit
$V_{CES}$	Collector-Emitter voltage	1200		V
$I_c$	Continuous collector current	$T_H = 25\text{ }^\circ\text{C}$	160	A
		$T_H = 80\text{ }^\circ\text{C}$	75	
$I_{CM}$	Pulsed collector current	$T_H = 25\text{ }^\circ\text{C}$	250	
$V_{GE}$	Gate-Emitter voltage	$\pm 20$		V
$P_D$	Power dissipation	470		W

The following table lists the electrical characteristics of MSCGLQ75DDU120CTBL3NG device.

**Table 1-2. Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero gate voltage collector current	$V_{GE} = 0\text{ V}$ $V_{CE} = 1200\text{ V}$		—	—	50	$\mu\text{A}$
$V_{CE(\text{sat})}$	Collector emitter saturation voltage	$V_{GE} = 15\text{ V}$ $I_C = 75\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	1.7	2.05	2.4	V
			$T_J = 150\text{ }^\circ\text{C}$	—	2.6	—	
$V_{GE(\text{th})}$	Gate threshold voltage	$V_{GE} = V_{CE}$ $I_C = 2.6\text{ mA}$		5.3	5.8	6.3	V
$I_{GES}$	Gate-Emitter leakage current	$V_{GE} = 20\text{ V}$ $V_{CE} = 0\text{ V}$		—	—	150	nA

# MSCGLQ75DDU120CTBL3NG

## Electrical Specifications

The following table lists the dynamic characteristics of MSCGLQ75DDU120CTBL3NG device.

**Table 1-3. Dynamic Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
C <sub>ies</sub>	Input capacitance	V <sub>GE</sub> = 0 V V <sub>CE</sub> = 25 V f = 1 MHz		—	4400	—	pF
C <sub>oes</sub>	Output capacitance			—	250	—	
C <sub>res</sub>	Reverse transfer capacitance			—	235	—	
Q <sub>g</sub>	Gate charge	V <sub>GE</sub> = 15 V V <sub>CE</sub> = 960 V I <sub>C</sub> = 75 A		—	325	—	nC
T <sub>d(on)</sub>	Turn-on delay time	V <sub>GE</sub> = ±15 V V <sub>Bus</sub> = 600 V I <sub>C</sub> = 75 A R <sub>G</sub> = 6.4 Ω	T <sub>J</sub> = 150 °C	—	30	—	ns
T <sub>r</sub>	Rise time			—	49	—	
T <sub>d(off)</sub>	Turn-off delay time			—	366	—	
T <sub>f</sub>	Fall time			—	48	—	
E <sub>on</sub>	Turn-on switching energy	V <sub>GE</sub> = ±15 V V <sub>Bus</sub> = 600 V	T <sub>J</sub> = 150 °C	—	3.84	—	mJ
E <sub>off</sub>	Turn-off switching energy	I <sub>C</sub> = 75 A R <sub>G</sub> = 6.4 Ω		—	3.84	—	
R <sub>G</sub>	Integrated gate resistor			—	10	—	Ω
I <sub>SC</sub>	Short circuit data	V <sub>GE</sub> ≤ 15 V V <sub>Bus</sub> = 900 V t <sub>p</sub> ≤ 10 μs	T <sub>j</sub> = 150 °C	—	260	—	A
R <sub>thJH</sub>	Junction-to-heatsink thermal resistance	λ <sub>paste</sub> = 3.4 W/mK		—	0.318	—	°C/W

**1.2****SiC Diode Ratings and Characteristics (Per SiC Diode)**

The following table lists the SiC diode ratings and characteristics of MSCGLQ75DDU120CTBL3NG device.

**Table 1-4. SiC Diode Ratings and Characteristics**

<b>Symbol</b>	<b>Characteristic</b>	<b>Test Conditions</b>		<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
$V_{RRM}$	Peak repetitive reverse voltage				—	—	1200 V
$I_{RM}$	Reverse leakage current	$V_R = 1200 \text{ V}$	$T_J = 25 \text{ }^\circ\text{C}$	—	10	200	$\mu\text{A}$
			$T_J = 175 \text{ }^\circ\text{C}$	—	250	—	
$I_F$	DC forward current		$T_H = 100 \text{ }^\circ\text{C}$	—	50	—	A
$V_F$	Diode forward voltage	$I_F = 50 \text{ A}$	$T_J = 25 \text{ }^\circ\text{C}$	—	1.5	1.8	V
			$T_J = 175 \text{ }^\circ\text{C}$	—	2.1	—	
$Q_C$	Total capacitive charge	$V_R = 600 \text{ V}$		—	224	—	nC
$C$	Total capacitance	$f = 1 \text{ MHz}$ $V_R = 400 \text{ V}$		—	246	—	pF
		$f = 1 \text{ MHz}$ $V_R = 800 \text{ V}$		—	182	—	
$R_{thJH}$	Junction-to-heatsink thermal resistance	$\lambda_{\text{paste}} = 3.4 \text{ W/mK}$		—	0.635	—	°C/W

**1.3****Thermal and Package Characteristics**

The following table lists the thermal and package characteristics of the MSCGLQ75DDU120CTBL3NG device.

**Table 1-5. Thermal and Package Characteristics**

<b>Symbol</b>	<b>Characteristic</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
$V_{ISOL}$	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz	2500	—	—	V
$T_J$	Operating junction temperature range	-55	—	175	°C
$T_{JOP}$	Recommended junction temperature under switching conditions	-55	—	$T_{Jmax}-25$	
$T_{STG}$	Storage case temperature	-55	—	125	
$T_C$	Operating case temperature	-55	—	125	
Torque	Mounting torque	0.7	—	0.9	N.m
Wt	Package weight	—	32.5	—	g

# MSCGLQ75DDU120CTBL3NG

## Electrical Specifications

The following table lists the temperature sensor NTC of the MSCGLQ75DDU120CTBL3NG device.

**Table 1-6. Temperature Sensor NTC**

Symbol	Characteristic	Min	Typ	Max	Unit
R <sub>25</sub>	Resistance at 25 °C	—	50	—	kΩ
ΔR <sub>25</sub> /R <sub>25</sub>		—	5	—	%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K	—	3952	—	K
ΔB/B	—	T <sub>C</sub> = 100 °C	—	4	%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]} \quad T: \text{Thermistor temperature}$$

R<sub>T</sub>: Thermistor value at T

**Note:** See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

## 1.4 Typical IGBT4 Performance Curve (Per IGBT)

This section shows the typical IGBT4 performance curves of MSCGLQ75DDU120CTBL3NG device.

**Figure 1-1. Junction-to-Heatsink Thermal Impedance**

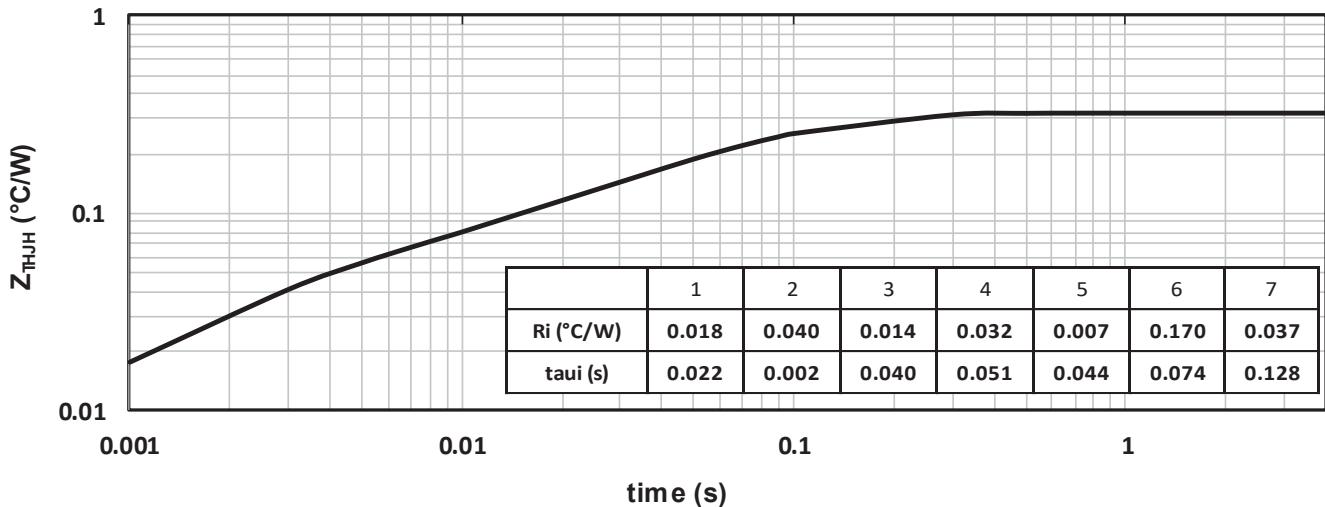


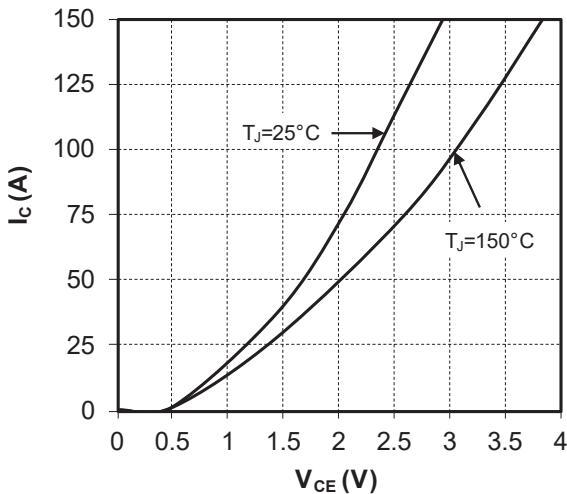
Figure 1-2. Output Characteristics ( $V_{GE} = 15$  V)

Figure 1-3. Output Characteristics

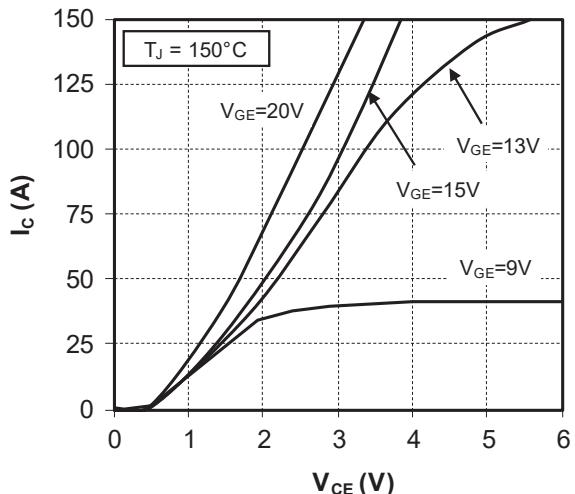


Figure 1-4. Transfer Characteristics

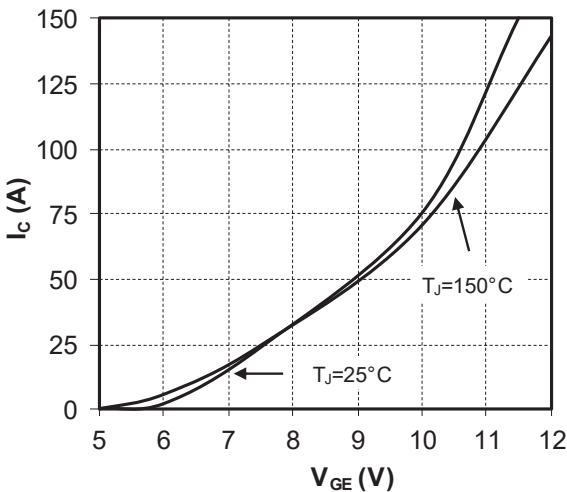


Figure 1-5. Energy Losses vs. Collector Current

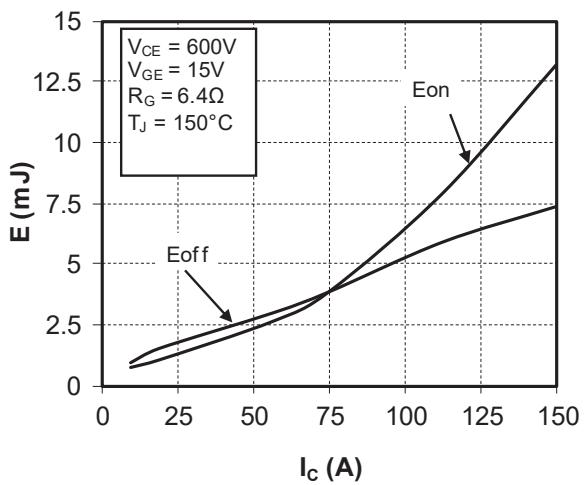


Figure 1-6. Switching Energy Losses vs. Gate Resistance

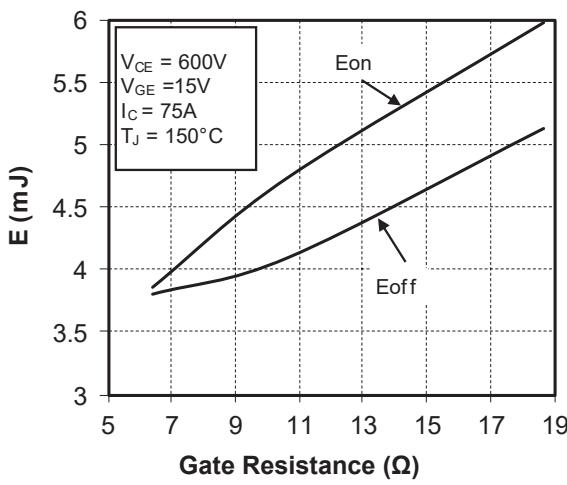
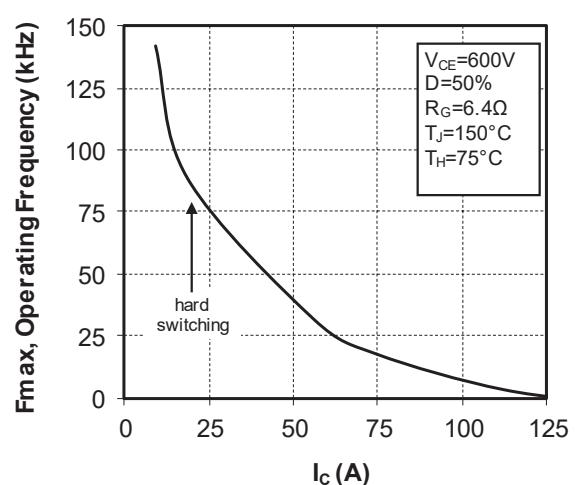


Figure 1-7. Operating Frequency vs. Collector Current

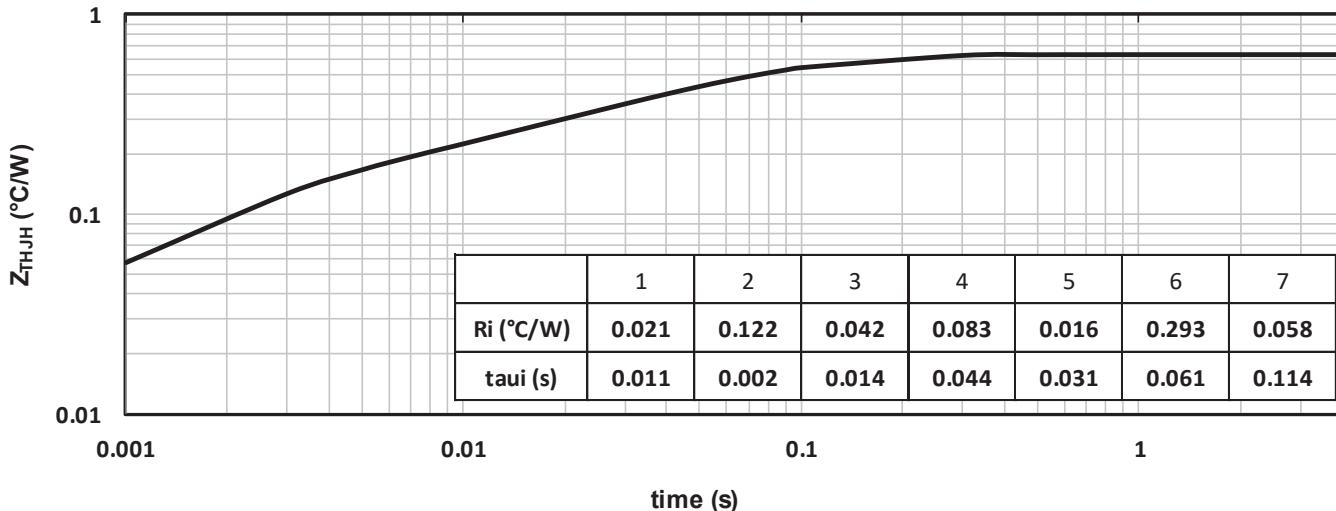


## 1.5

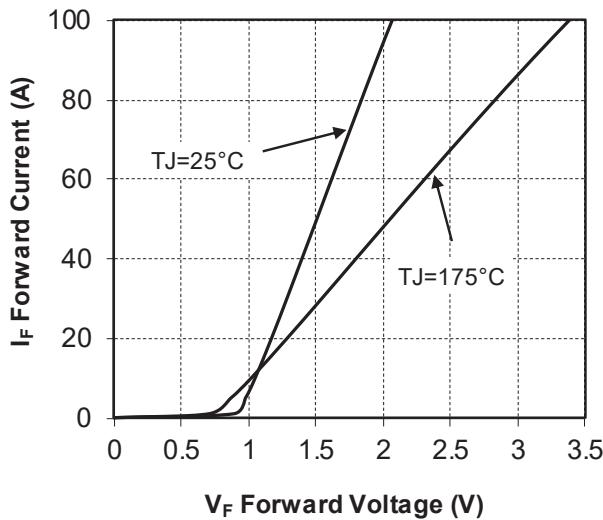
### Typical SiC Diode Performance Curves (Per SiC Diode)

This section shows the typical SiC diode performance curves of MSCGLQ75DDU120CTBL3NG device.

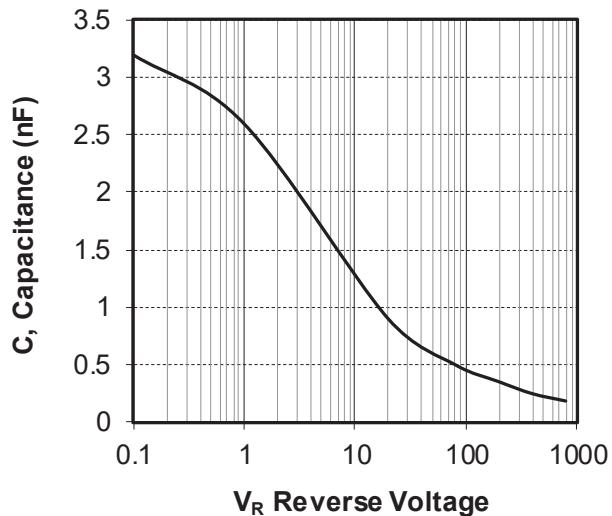
**Figure 1-8. Junction-to-Heatsink Thermal Impedance**



**Figure 1-9. Forward Characteristics**



**Figure 1-10. Capacitance vs. Reverse Voltage**



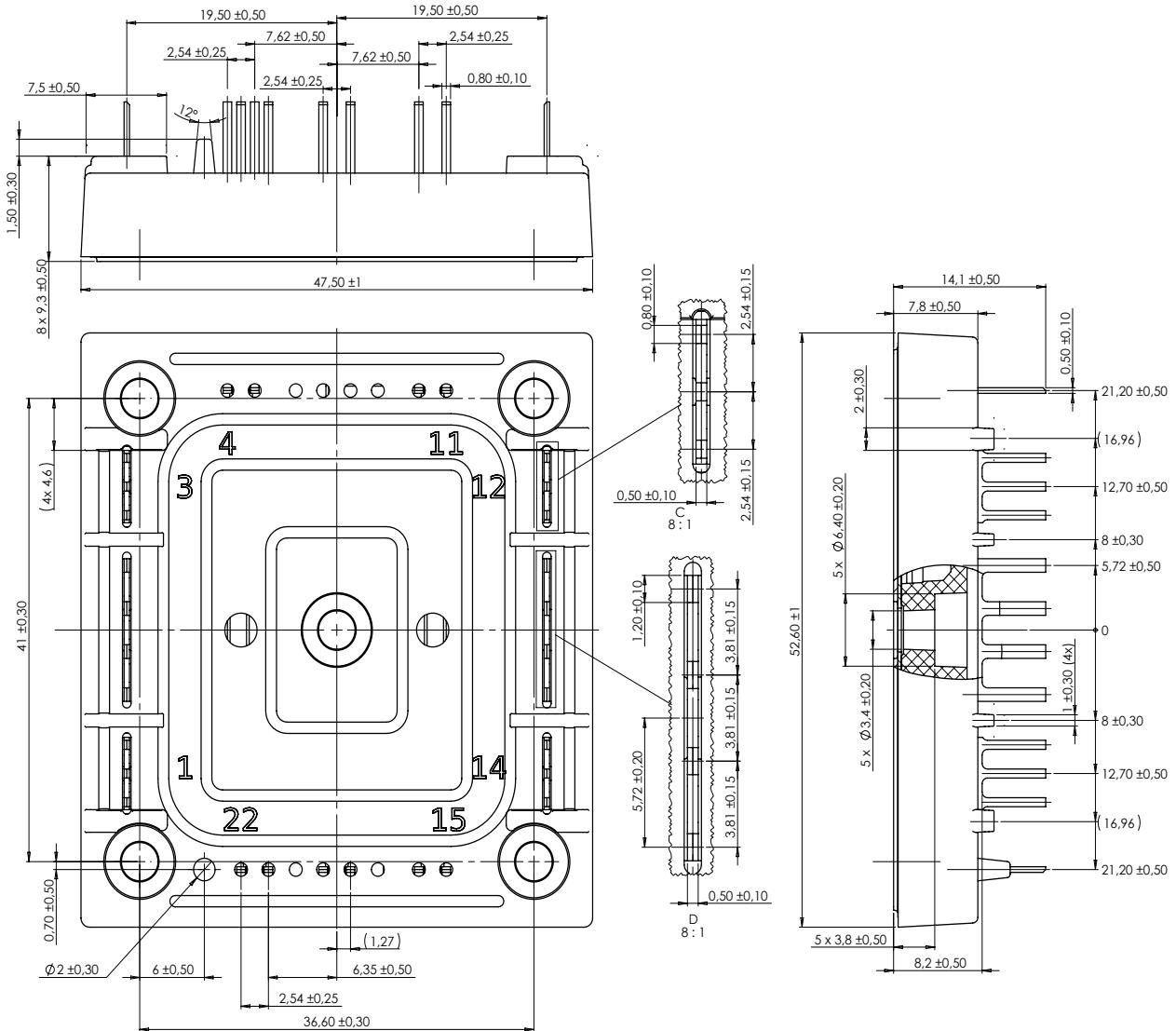
## 2. Package Specifications

The following section shows the package specification of MSCGLQ75DDU120CTBL3NG device.

### 2.1 Package Outline

The following figure shows the package outline drawing of MSCGLQ75DDU120CTBL3NG device. The dimensions in the following figure are in millimeters.

**Figure 2-1. Package Outline Drawing**



**3. Revision History**

Revision	Date	Description
A	07/2021	Initial revision

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[FS150R17N3E4\\_B11](#) [FS20R06W1E3\\_B11](#) [FS30R06W1E3\\_B11](#) [FS75R12KE3G](#) [FS75R12W2T4\\_B11](#) [FZ1600R17HP4\\_B2](#)  
[FZ300R12KE3G](#) [FZ400R17KE3](#) [FZ400R17KE4](#) [FZ600R65KE3](#) [DF1000R17IE4D\\_B2](#) [APTGT75DA60T1G](#) [DZ800S17K3](#) [F12-](#)  
[25R12KT4G](#) [F3L200R12W2H3\\_B11](#) [F3L300R12ME4\\_B22](#) [F3L75R07W2E3\\_B11](#) [F4-150R12KS4](#) [F475R07W1H3B11ABOMA1](#)  
[FD1400R12IP4D](#) [FD400R12KE3\\_B5](#)